# ISD1447AS1

FOR LOW FREQUENCY POWOR AMPLIFY APPLICATION SILICON NPN EPITAXIAL TYPE

### **DESCRIPTION**

ISD1447AS1 is a silicon NPN epitaxial type transistor designed for 2 to 3.5W output low frequency power amplify application. Complementary with ISB1035AS1.

### **FEATURE**

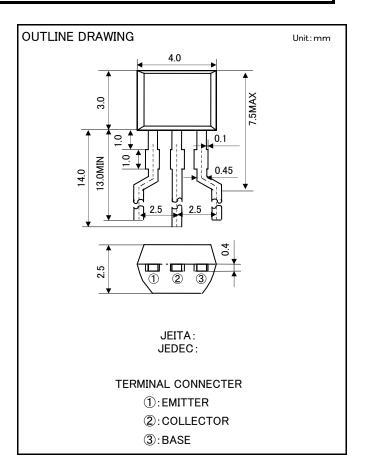
- lacktriangle High collector current.  $I_{\text{CM}}$ = 1.5A
- High gain band width product. fT= 100MHz typ
- High collecot dissipation. Pc= 600mW
- ●Excellent linearity of DC forward current gain.

### **APPLICATION**

2 to 3.5W output low frequency amplify circuit of radio, cassette tape recorder, mini stereo.

#### MAXIMUM RATINGS (Ta=25°C)

Symbol	Parameter	Parameter Ratings	
Vcво	VcBo Collector to Base voltage		٧
VEBO	Emitter to Base voltage	4	٧
Vceo	Collector to Emitter voltage	25	٧
$I_{C}$	Collector current	1	Α
I <sub>CM</sub>	Peak collector current	1.5	Α
P <sub>c</sub>	Collector dissipation	600	mW
$T_{j}$	Junction temperature	+150	ပွ
$T_{stg}$	Storage temperature	−55 <b>~</b> +150	သိ



### ELECTRICAL CHARACTERISTICS (Ta=25°C)

Parameter	Parameter	Test conditions	Limits			Unit
Parameter		Test conditions	Min	Тур	Max	Unit
V(BR)cB0	C to B break down voltage	$I_{\text{C}}$ = 10 $\mu$ A , $I_{\text{E}}$ =0mA	30	-	-	٧
V(BR)EBO	E to B break down voltage	$I_{\rm E}$ = 10 $\mu$ A , $I_{\rm C}$ =0mA	4	-	-	٧
V(BR)ceo	C to E break down voltage	I <sub>C</sub> = 100 μ A , RBE= ∞	25	-	-	٧
ICBO	Collector cut off current	$V_{CB}$ = 25 $V$ , $I_{E}$ = 0mA	-	-	1	μΑ
ĪEBO	Emitter cut off current	V $_{\rm EB}$ =2V , I $_{\rm C}$ = 0mA	-	-	1	μΑ
hFE※	DC forward current gain	$V_{CE} = 1V$ , $I_{C} = 500$ mA	55	-	300	_
VCE(sat)	C to E Saturation Voltage	I $_{\rm C}$ =500mA , I $_{\rm B}$ = 25mA	_	_	0.5	٧
fT	Gain band width product	V <sub>CE</sub> =6V , I <sub>E</sub> = -10mA	_	100	_	MHz

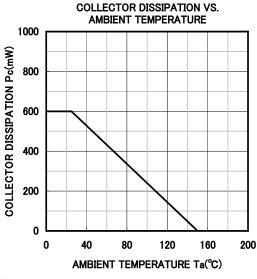
※) It shows hFE classification in right table.

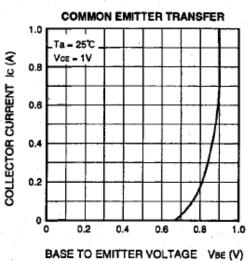
Item		С	D	Е	
	hFE item	55 <b>~</b> 110	90~180	150~300	

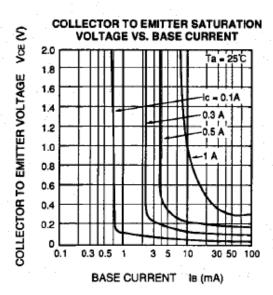
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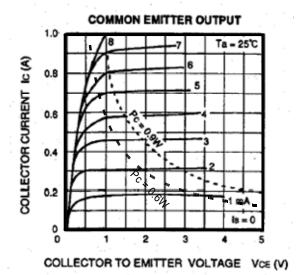
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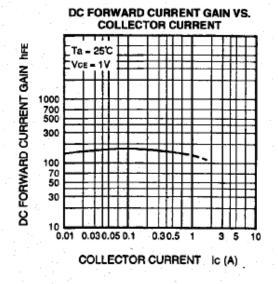
#### TYPICAL CHARACTERISTICS













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